

SAMTM Data Sheet SAM-1550-4-4ps-x, λ = 1550 nm

Laser wavelength $\lambda = 1550 \text{ nm}$

High reflection band $\lambda = 1480 ... 1580 \text{ nm}$

Absorbance $A_0 = 4 \%$ Modulation depth $\Delta R = 2.4 \%$ Non-saturable loss $A_{ns} = 1.6 \%$

Saturation fluence $\Phi_{sat} = 180 \,\mu\text{J/cm}^2$

Relaxation time constant $\tau \sim 4 \text{ ps}$ Damage threshold 2 mJ/cm^2

Chip area 4.0 mm x 4.0 mm; other dimensions on request

Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

x = 0
x = 12.7 g
x = 25.4 g
x = 12.7 s
x = 12.7 s
x = 12.7 s
x = 12.7 s
x = 25.4 s
x = 25.4 s
x = 25.4 s
x = 25.0 w
x

Low intensity spectral reflectance

